

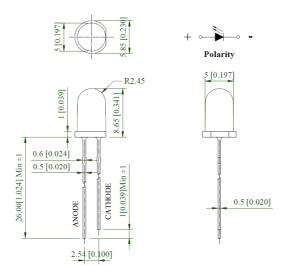
Features

- High reliability
- General purpose leads
- Peak wavelength λp=940nm
- Mechanically and spectrally matched to the phototransistor
- Low forward voltage
- High radiant intensity

Applications

- Optoelectronic Switch
- IR Touch-Panel
- Industrial IR Equipment
- Consumer Electronics
- High Speed IR Communications

Package Dimensions in mm



Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ± 0.25 mm (.010 //) unless otherwise noted.

Figure 1. INL-5AHIR15 Package Dimensions

Description

- The infrared emitting diode (940nm) is a high intensity diode, molded in a water clear transparent plastic package.
- The device is spectrally matched with silicon photodiode and phototransistor.



Absolute Maximum Rating at 25°C (Note 1)

Product	Emission Color	P _d (mW)	I _F (mA)	I _{FP} * (A)	V _R (V)	T _{OP} (°C)	T _{ST} (°C)
INL-5AHIR15	Infrared	150	100	1	5	-40°C~+80°C	-40°C~+85°C

Notes

1. Condition for IFP is pulse of 1/10 duty and 1kHz frequency

Electrical Characteristics $T_A = 25^{\circ}$ (Note 1)

5	Emission Color	l _F (mA)	V _F (V)		λ(nm)			Viewing Angle	Ee(mW/sr)	
Product			min	max	λ_{D}	λ_{P}	Δλ	2 <i>0</i> 1/2	min	typ.
INL-5AHIR15	Infrared	20	0.8	1.5	-	940	50	15	7.8	12

Notes

1. Performance guaranteed only under conditions listed in above tables.

ESD Precaution

ATTENTION: Electrostatic Discharge (ESD) protection

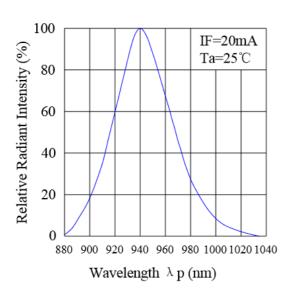
The symbol above denotes that ESD precaution is needed. ESD protection for GaP and AlGaAs based chips is necessary even though they are relatively safe in the presence of low static-electric discharge. Parts built with AlInGaP, GaN, or/and InGaN based chips are STATIC SENSITIVE devices. ESD precaution must be taken during design and assembly. If manual work or processing is needed, please ensure the device is adequately protected from ESD during the process.

Please be advised that normal static precautions should be taken in the handling and assembly of this device to prevent damage or degradation which may be induced by electrostatic discharge (ESD).

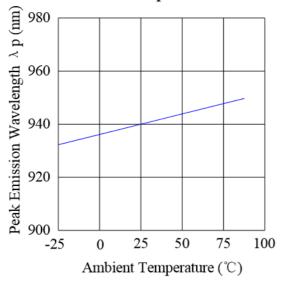


Typical Characteristic Curves

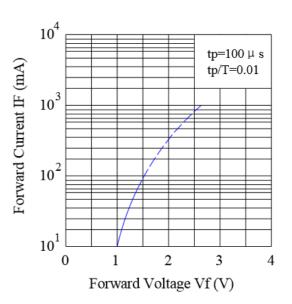
Spectral Distribution



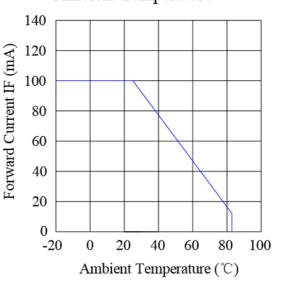
Peak Emission Wavelength & Ambient Temperature



Forward Current & Forward Voltage

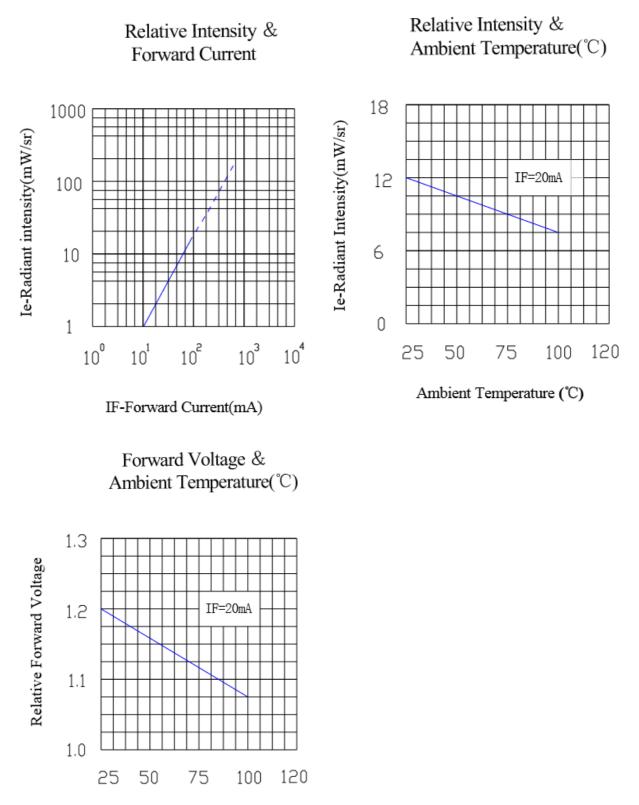


Forward Current & Ambient Temperature





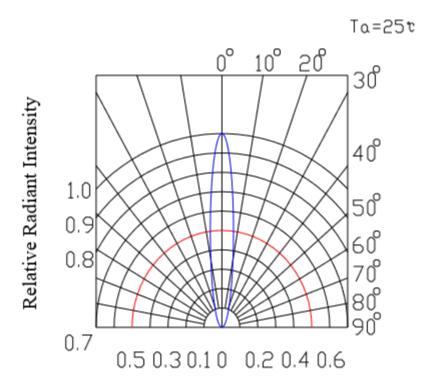
INL-5AHIR15 5mm Infrared Emitting Diode Though Hole Lamp LED



Ambient Temperature (°C)



Typical Characteristic Curves – Radiation Pattern

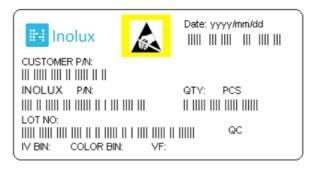


Ordering Information

Product	Emission Color	Technology	Test Current I _F (mA)	Radiant Intensity Ee (mW/sr) (Typ.)	Forward Voltage V _F (V) (Typ.)	Orderable Part Number
INL-5AHIR15	Infrared	AlGaAs	20	12	1.2	INL-5AHIR15



Label Specifications



Inolux P/N:

I	Ν		L	-	5	А	-	HIR	1	5		х	х	Х	Х
	Package		kage	Lens	Color	View Angle			Customized Stamp-off						
	Inole Imp 1		ре		stan	۹ = dard ۱m	(Blank) = clear	HIR = 940nm	15 =	15 deg.					

Lot No.:

Z	2	0	1	7	01	24	001
Internal		Year (2017	2018)	Month	Date	Serial	
Tracker			, 2018,)	WOITCH	Date	Serial	



Reliability

Item	Frequency/ lots/ samples/ failures	Standards Reference	Conditions		
Precondition	For all reliability monitoring tests according to JEDEC Level 2	J-STD-020	1.) Baking at 85°C for 24hrs 2.) Moisture storage at 85°C/ 60% R.H. for 168hrs		
Solderability	1Q/ 1/ 22/ 0	JESD22-B102-B And CNS-5068	Accelerated aging 155°C/ 24hrs Tinning speed: 2.5+0.5cm/s Tinning: A: 215°C/ 3+1s or B: 260°C/ 10+1s		
Resistance to soldering heat		CNS-5067	Dipping soldering terminal only Soldering bath temperature A: 260+/-5°C; 10+/-1s B: 350+/-10°C; 3+/-0.5s		
Operating life test	1Q/ 1/ 40/ 0	CNS-11829	1.) Precondition: 85°C baking for 24hrs 85°C/ 60%R.H. for 168hrs 2.) Tamb25°C; IF=20mA; duration 1000hrs		
High humidity, high temperature bias	1Q/ 1/ 45/ 0	JESD-A101-B	Tamb: 85°C Humidity: 85% R.H., IF=5mA Duration: 1000hrs		
High temperature bias	1Q/ 1/ 20	IN specs.	Tamb: 55°C IF=20mA Duration: 1000hrs		
Pulse life test	1Q/ 1/ 40/ 0		Tamb25°C, If=20mA,, Ip=100mA, Duty cycle=0.125 (tp=125 μ s,T=1sec) Duration 500hrs)		
Temperature cycle	1Q/ 1/ 76/ 0	JESD-A104-A IEC 68-2-14, Nb	A cycle: -40 degree C 15min; +85 degree C 15min Thermal steady within 5 min 300 cycles 2 chamber/ Air-to-air type		
High humidity storage test	1Q/ 1/ 40/ 0	CNS-6117	60+3°C 90+5/-10% R.H. for 500hrs		
High temperature storage test	1Q/ 1/ 40/ 0	CNS-554	100+10°C for 500hrs		
Low temperature storage test	1Q/ 1/ 40/ 0	CNS-6118	-40+5°C for 500hrs		



Revision History

Changes since last revision	Page	Version No.	Revision Date
Initial Release		1.0	01-19-2019

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Mouser Electronics

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Inolux: INL-5AHIR15